

FORM PTO-1449
(REV. 7-80)U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICEATTY. DOCKET NO.
500996.01APPLICATION NO.
09/965,240

INFORMATION DISCLOSURE STATEMENT

(Use several sheets if necessary)

APPLICANT(S)

Randhir P.S. Thakur et al.

FILING DATE

September 26, 2001

GROUP ART UNIT

2825

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
VY	AA	5,639,684	06/17/97	Kwok	437	60	—
VY	AB	5,866,938	02/02/99	Takagi et al.	257	530	—
VY	AC	6,458,645 B2	10/01/02	DeBoer et al.	438	240	—
VY	AD	6,515,343 B1	02/04/03	Shroff et al.	257	530	—
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO
	AK							
	AL							
	AM							
	AN							
	AO							

OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.)

VY	AP	Kim, J. et al., "High Performance Antifuse with Planar Double Dielectrics on Si1-xGex Pad for Field Programmable Gate Array Applications", IEEE Electronic Letters, Vol. 32, No. 24, pp. 2276-2277, November 21, 1996.
	AQ	
	AR	

EXAMINER

11/11/03

V. Yeager

DATE CONSIDERED

* EXAMINER: Initial if reference considered, whether or not criteria is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant(s).